

AP386X

General Description

The AP386X is a low-cost high-resolution single chip solution for APA (All point addressable) capacitive touch screen. It is an 8-bit single cycle 8051 microcontroller with ICP Interface. The chip includes 12-bit successive approximation analog-to-digital converters with an I²C interface and multiplexer-switcher circuits for flexible measurement of analog signal from APA panel. An accurate switched-capacitor integrator is built-in and it can auto calibrate the pixel parameters for a wide range of capacitance on the touch screen (1pF to 32pF). This touch screen controller (TSC) with CMOS integration circuit provides an ideal choice for APA touch panel. The AP386X is specified over the temperature range of -40°C to 85°C.

The AP386X is available in QFN- $5\times5-40$ (for AP3860) and QFN- $6\times6-48$ (for AP3861) packages.

Features

- Mutual Capacitive Touch Sensing
- Single Power Supply: 2.8V to 3.6V Operation Voltage; LDO inside to Support 1.6V to 2.0V Operation Voltage
- Up to 17/23 Drive Lines and 10/12 Sense Lines
- Charge Pump Support up to 6V, Doubling SNR
- Internal Two-wire Serial Control Bus I²C
- Single-end Integrator with Programmable Gain Control
- Multiplexed Analog Digitization with 12-bit Resolution Scan SAR ADCs and Its Dedicated 2X to 8X Accumulator XSRAM Buffers

Features (Continued)

- Single Cycle 8051 CPU Core, Maximum Operating Clock up to 28MHz from IOSC (Zero Wait State)
 - 4 to 28MHz Internal Oscillator (IOSC)
 - 32k-byte Flash ROM
 - 6k-byte Internal SRAM
 - Two 16-bit Timers T0/T1
 - Configurable I²C Slave Controller and SPI Slave Controller Shared with the Same Ports
 - With Asynchronous I²C Slave Address
 Detection Logic Design
 - 4 General Purpose GPIO Pins One External Interrupt Pin
- ISP/IAP via I²C Port
- Operation Temperature Range: -40°C to 85°C
- Package Type Alternatives: QFN-5×5-40 and QFN-6×6-48
- RoHS Compliance
- Operating Mode:

Mode	Description
Power-down	No scan with power-down mode
Idle	While only 8051 CPU core is idle,
	all peripherals remain active
Standard	Higher scan rate when fingers are
	on panel, IOSC can up to 4MHz
	to 28MHz

Applications

- Mobile Phones
- Personal Digital Assistants
- Smart Hand-held or Gaming Devices

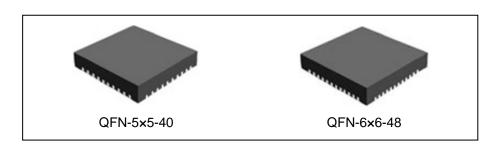


Figure 1. Package Types of AP386X



AP386X

Pin Configuration

FN Package (QFN-5×5-40)

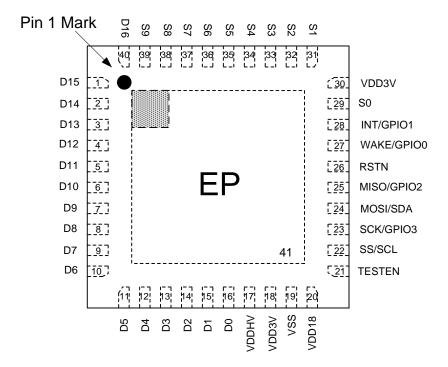
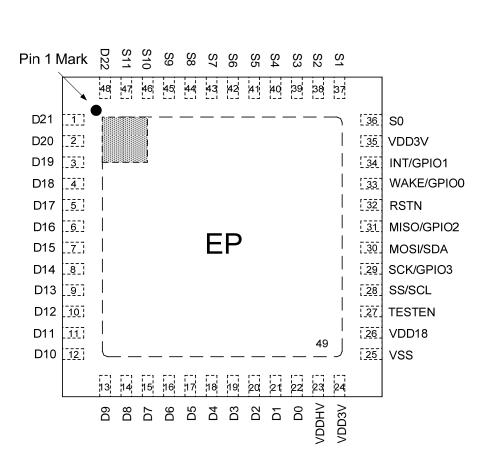


Figure 2. Pin Configuration of AP3860 (Top View)



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Pin Configuration (Continued)



FN Package (QFN-6×6-48)

Figure 3. Pin Configuration of AP3861 (Top View)



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Pin Description

Pin N	umber	D.	р.	
QFN-5×5-40 AP3860	QFN-6×6-48 AP3861	Pin Name	Pin Type	Pin Function
40, 1 to 16	6 to 22	D16 to D0	I/O, A	Driving Lines 16 to 0 These pins can also be configured as I/O bi-directional ports for test
-	48, 1 to 5	D22 to D17	I/O, A	Driving Lines 22 to 17These pins can also be configured as I/Obi-directional ports for test
17	23	VDDHV	0	High Voltage. 6VCharge pump high Voltage. This output pin can be configured as VDD3V or 6V accordingly
18, 30	24, 35	VDD3V	Р	Supply Voltage. 2.8V to 3.6VA good decoupling capacitor between VDD3V andVSS pins is critical for good performance
19	25	VSS	Р	Ground Voltage. 0V
				Internal Regulator Output. 1.6V to 2.0V
20	26	VDD18	0	Typical decoupling capacitors of 0.1μ F and 10μ F should be connected between VDD18 and VSS
21	27	TESTEN	Ι	Test Mode Enable High ActiveThis pin has an internal weakly pull low resistor connected. If it is connected high, the chip enters into Test Mode condition
22	28	SS/SCL	I/O	SS/SCL This pin can be configured as the SCL signal of the I^2C master or I^2C slave controller. When I^2C is enabled, the pin is configured as an open-collector. While in SPI mode, this pin is configured as the slave chip select pin
23	29	SCK/ GPIO3	I/O	Port 1.3 GPIO 8051 P1.3 GPIO. This pin can also be configured as the serial clock from SPI master while SPI interface is activated
24	30	MOSI/ SDA	I/O	SDA This pin can be configured as the SDA signal of the I^2C master or I^2C slave controller. In this operation mode, this pin should also be configured as open-collector. While SPI interface is selected, the pin serves as the data port from SPI master to SPI slave
25	31	MISO/ GPIO2	I/O	Port 1.2 GPIO 8051 P1.2 GPIO. This pin can also be configured as the output data pin from slave to master for SPI interface



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Pin Description (Continued)

Pin Nu	umber	D.	D '				
QFN-5×5-40 AP3860	QFN-6×6-48 AP3861	Pin Name	Pin Type	Pin Function			
				Reset Low Active			
26	32	RSTN	Ι	Typically connect a resistor to VDD3V and a capacitor to VSS. Low asserted and threshold at $0.5*V_{DD}$. When forced low, the chip enters into reset condition. This pin should not be connected to any level above V_{DD}			
		WAKE/		Port 1.0 GPIO			
27	33	GPIO0	I/O	8051 P1.0 GPIO. This pin can also be configured as the wakeup pin from the host			
				Port 1.1 GPIO			
28	34	INT/ GPIO1	I/O	8051 P1.1 GPIO. Open Drain output. This pin can also be configured as the interrupt pin to notify the host			
				Sensing Lines 0 to 9			
29, 31 to 39	36 to 45	S0 to S9	I/O, A	These pins can also be configured as I/O bi-directional ports for test			
				Sensing Lines 10 to 11			
-	46, 47	S10, S11	I/O, A	These pins can also be configured as I/O bi-directional ports for test			
41	49	EP		Exposed Pad			

"I/O" means input/output; "I" means input; "O" means Output; "P" means power; "A" means analog.

SCL and SDA Pin Description

Pull-up Enable

The pull-up enable for SCL and SDA is activated for AP386X, meaning that AP386X always has pull-up SCL and SDA to VDD3V. During reset, SCL and SDA are as input pin. Moreover, if the pin connecting to the system is floating, the internal pull-up will tie the pin to VDD3V ($10k\Omega$). After AP386X is reset, SCL and SDA are input until its corresponding register is configured.

Mode Selection

SCL and SDA can be used in I²C and SPI mode. AP386X can enable I²C mode (SCL and SDA configured as open drain pin) by register setting.

Wakeup

SCL and SDA can be used for wakeup input signals in different mode. While I²C mode is enabled, a START protocol (SDA is low and SCL is high) on SCL and SDA is a wakeup signal to AP386X. While SPI mode is enabled, an active low on the pin of SCL (serving as a slave select in SPI) is a wakeup signal to AP386X. Moreover, a wakeup signal can be asserted by host from GPIO0.

INT/GPIO1

GPIO1 can be configured as open-drain or push-pull mode. Furthermore, GPIO1 pin has internal pull-up to VDD3V ($60k\Omega$) or VDD18 ($10k\Omega$) based on different register definition.



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Functional Block Diagram

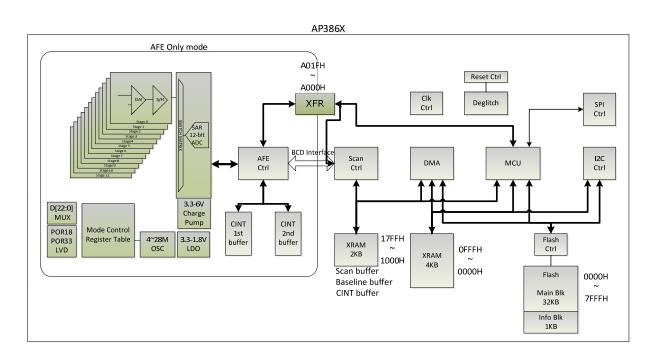
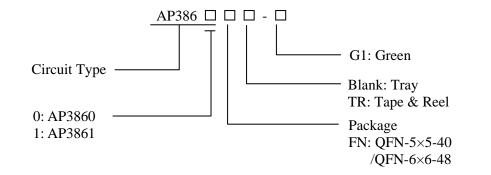


Figure 4. Functional Block Diagram of AP386X



AP386X

Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing Type
QFN-5x5-40		AP3860FNTR-G1	3860FN	Tape & Reel
OEN 6x6 49	-40 to 85°C	AP3861FN-G1	3861FN	Tray
QFN-6x6-48		AP3861FNTR-G1	3861FN	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "G1" in the part number, are RoHS compliant and green.

AP386X Support 3" to 8" Touch Panel, Listed Below:

PN	TX/RX	Multi-touch	Package	Panel size
AP3860	17/10	10 points 100Hz	QFN-5x5-40	3" to 7"
AP3861	23/12	10 points 100Hz	QFN-6x6-48	4" to 8"



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Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value	Unit
Supply Voltage (Pin VDD3V)	V_{DD}	0 to 4	V
Analog Input Voltage (Other pins)		-0.3 to V _{DD} +0.3	V
Logic Input Voltage		-0.3 to V _{DD} +0.3	V
Thermal Resistance (Simulation, Junction to Ambient)	θ_{JA}	TBD	°C/W
Maximum Junction Temperature	TJ	100	°C
Operating Temperature	T _{OP}	-40 to 85	°C
Storage Temperature	T _{STG}	-65 to 150	°C
ESD (Human Body Model)	ESD HBM	8000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage (Pin VDD3V)	V _{DD}	2.8	3.6	V
Operating Ambient Temperature	T _A	-40	85	°C



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Electrical Characteristics

 $T_A=25^{\circ}C$, $V_{DD}=2.8V$ to 3.6V, I^2C bus frequency=400kHz, 12-bit mode, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
		Standard mode f _{OSC} =4 to 28MHz		5		mA
Quiescent Current		Power-down mode			1	μΑ
		Idle mode		60		μΑ
VDD18 Output Voltage	V_{DD18}		1.6	1.8	2.0	V
Charge Pump Voltage	V _{DDHV}	Charge pump enable	5.8	6	6.3	V
Internal Operating Frequency	$\mathbf{f}_{\mathrm{OSC}}$		4		28	MHz

DA/AC Characteristics for AFE

Parameter	Symbol	Conditions	Min	Тур	Max	Unit			
ADC DC Accuracy									
Resolution					12	Bits			
No Missing Codes		Standard modes	11	12		Bits			
Integral Linearity Error	INL	Standard modes		±3		LSB			
Differential Linearity				±1.5		LSB			
Error	DNL								
Offset Error	DINL				±6	LSB			
Gain Error					±4	LSB			
Analog Input									
Full-scale Input Span			0		V _{DD}	V			
ADC Sampling Dynamics									
Throughput Rate				500		ksps			
Switched-capacitor Integr	ator								
Output Voltage Range			0.3		V _{DD} -0.3	V			
Integrator Capacitor	C _{INT}			40		pF			



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Electrical Characteristics (Continued) DA/AC Characteristics for 8051 CPU Core, Digital GPIO Pins, Digital Peripherals

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
RSTN Input Voltage	V _{RSTN_H}	Low to high level	1.56		1.71	- V
Threshold	V _{RSTN_L}	High to low level	1.16		1.30	V
Input High Voltage	V _{IH}		$0.7*V_{DD}$		V _{DD}	V
Input Low Voltage	V _{IL}		-0.3		0.5	V
Output High Voltage	V _{OH}		V _{DD} -0.6			V
Output Low Voltage	V _{OL}				0.4	V
High Level Output Current	I _{OH}	@V _{OH} (Min)		1		mA
Low Level Output Current	I _{OL}	@V _{OL} (Max)		1		mA
Internal Dull up Desistance	R _{PU}	SCL, SDA, INT		10		- kΩ
Internal Pull-up Resistance		Other Pins	34		74	- KS2
Internal Pull-down Resistance	R_{PD}		29		86	kΩ
Output Rise Time	t _{RISE}	$C_{LOAD}=20pF$ and 10% to 90%		5		ns
Output Fall Time	t _{FALL}	$C_{LOAD}=20pF$ and 10% to 90%		5		ns
GPIO Output Operating Frequency		C _{LOAD} =20pF	0		5	MHz
SCK Frequency	f _{SCK}				2	MHz
SCL Clock Frequency	f _{SCLI2C}		0		400	kHz



Typical Application

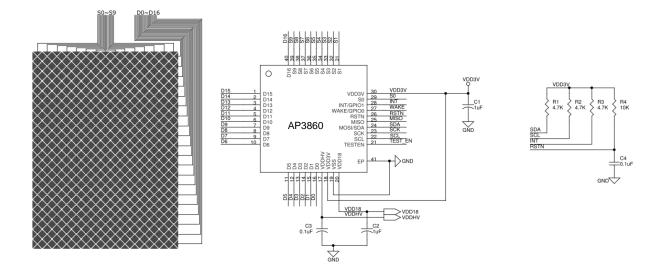


Figure 5. Typical Application Schematic of AP3860 (For QFN-5x5-40 Package)

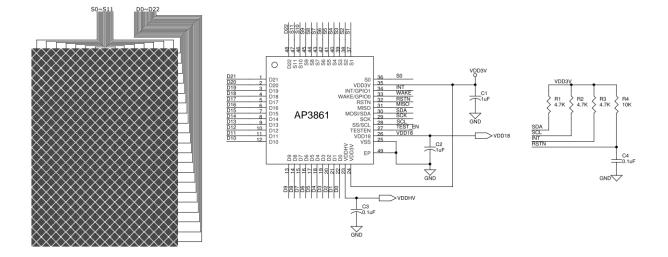


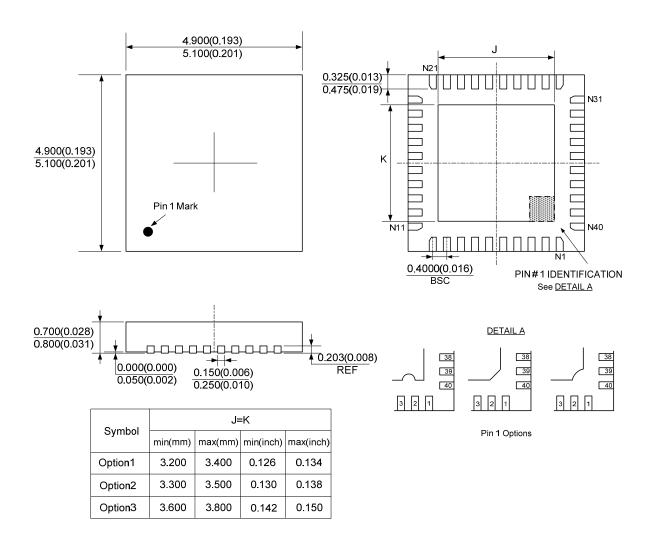
Figure 6. Typical Application Schematic of AP3861 (For QFN-6x6-48 Package)



QFN-5x5-40

Mechanical Dimensions

Unit: mm(inch)

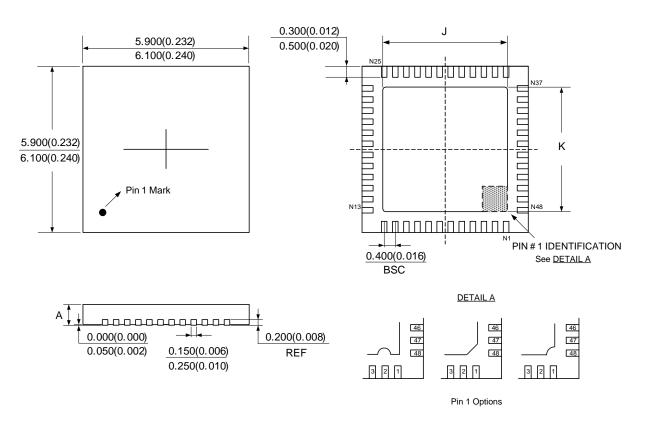




Mechanical Dimensions (Continued)

QFN-6×6-48

Unit: mm(inch)



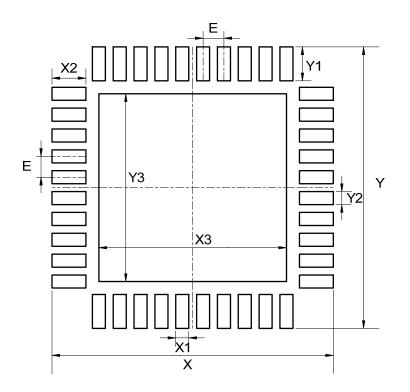
Symbol		J=	⊧K		A			
	min(mm)	max(mm)	min(inch)	max(inch)	min(mm)	max(mm)	min(inch)	max(inch)
Option1	4.400	4.600	0.173	0.181	0.700	0.800	0.028	0.031
Option2	4.150	4.450	0.163	0.175	0.800	0.900	0.031	0.035

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Mounting Pad Layout

QFN-5×5-40

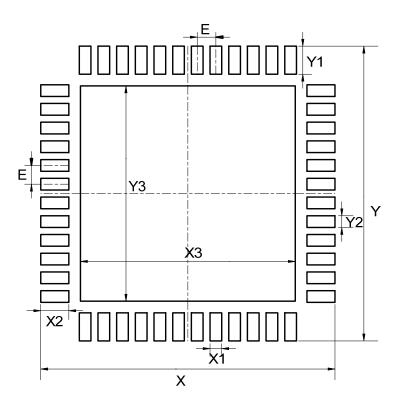


Dimensions	X=Y (mm)/(inch)	X1=Y2 (mm)/(inch)	Y1=X2 (mm)/(inch)	X3=Y3 (mm)/(inch)	E (mm)/(inch)
Option1	5.400/0.213	0.250/0.010	0.650/0.026	3.500/0.138	0.400/0.016
Option2	5.400/0.213	0.250/0.010	0.650/0.026	3.600/0.142	0.400/0.016
Option3	5.400/0.213	0.250/0.010	0.650/0.026	3.800/0.150	0.400/0.016



Mounting Pad Layout (Continued)

QFN-6×6-48



Dimensions	X=Y	X1=Y2	Y1=X2	X3=Y3	E
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	6.300/0.248	0.250/0.010	0.600/0.024	4.600/0.181	0.400/0.016



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